# **One Watt Amplifier Transistors**

### **PNP Silicon**

#### **Features**

• This is a Pb-Free Device\*

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	-30	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	V <sub>CBO</sub> -40	
Emitter - Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current – Continuous	Ic	-1.0	Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.0 8.0	W mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

### THERMAL CHARACTERISTICS

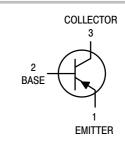
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

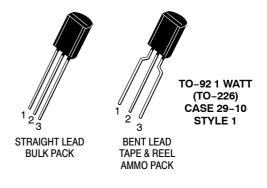
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



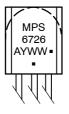
### ON Semiconductor®

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### **MARKING DIAGRAM**



= Assembly Location

= Year = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPS6726G	TO-92 (Pb-Free)	5000 Units / Bulk

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·			
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = -10 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)</sub> CEO	-30	-	Vdc
Collector – Base Breakdown Voltage ( $I_C = -100 \mu Adc$ , $I_E = 0$ )	V <sub>(BR)</sub> CBO	-40	-	Vdc
Emitter – Base Breakdown Voltage ( $I_E = -100 \mu Adc$ , $I_C = 0$ )	V <sub>(BR)EBO</sub>	-5.0	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -40 Vdc, I <sub>E</sub> = 0)	Ісво	_	-0.1	μAdc
Emitter Cutoff Current $(V_{EB} = -5.0 \text{ Vdc}, I_C = 0)$	l <sub>ЕВО</sub>	_	-0.1	μAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain ( $I_C = -100$ mAdc, $V_{CE} = -1.0$ Vdc) ( $I_C = -1000$ mAdc, $V_{CE} = -1.0$ Vdc)	h <sub>FE</sub>	60 50	_ 250	_
Collector – Emitter Saturation Voltage (I <sub>C</sub> = -1000 mAdc, I <sub>B</sub> = -100 mAdc)	V <sub>CE(sat)</sub>	-	-0.5	Vdc
Base – Emitter On Voltage (I <sub>C</sub> = –1000 mAdc, V <sub>CE</sub> = –1.0 Vdc)	V <sub>BE(on)</sub>	-	-1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS	<u> </u>	•	-	•
Collector-Base Capacitance (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>cb</sub>	_	30	pF
Small-Signal Current Gain (I <sub>C</sub> = -50 mAdc, V <sub>CE</sub> = -10 Vdc, f = 20 MHz)	h <sub>fe</sub>	2.5	25	-

<sup>1.</sup> Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2.0%.

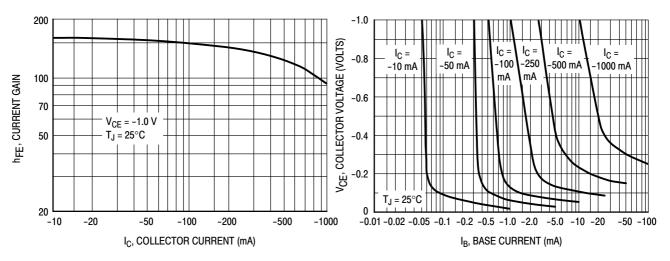


Figure 1. DC Current Gain

Figure 2. Collector Saturation Region

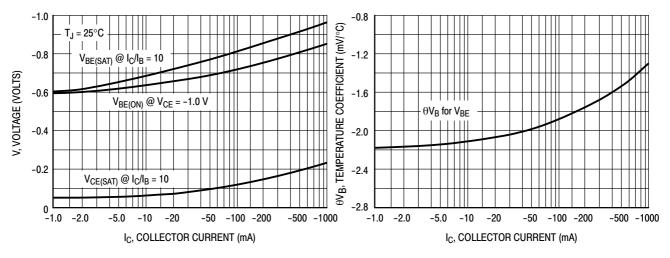


Figure 3. "ON" Voltages

**Figure 4. Temperature Coefficient** 

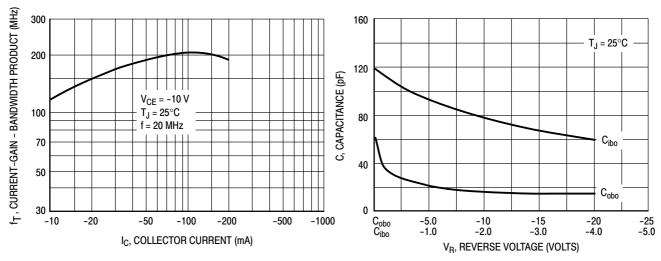


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

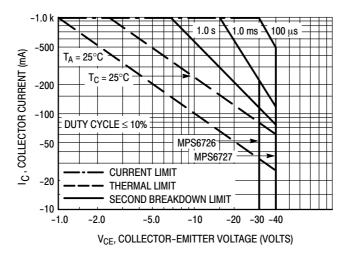
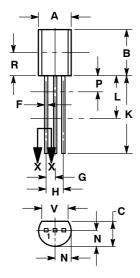


Figure 7. Active Region — Safe Operating Area

### PACKAGE DIMENSIONS

### TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE O**



STRAIGHT LEAD **BULK PACK** 



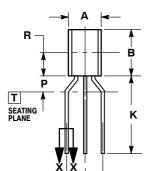
### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1994.
  CONTROLLING DIMENSION: INCHES.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DI-MENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLE 1: PIN 1. EMITTER

BASE COLLECTOR



**BENT LEAD** TAPE & REEL AMMO PACK



#### NOTES

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Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
V	0.135		3.43	

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